

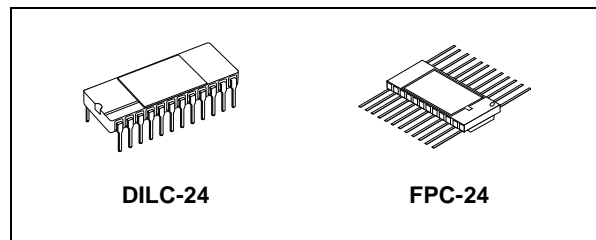


RAD-HARD 4 TO 16 LINE DECODER/DEMULTIPLEXER

- HIGH SPEED:
 $t_{PD} = 16\text{ns}$ (TYP.) at $V_{CC} = 6\text{V}$
- LOW POWER DISSIPATION:
 $I_{CC} = 4\mu\text{A}$ (MAX.) at $T_A=25^\circ\text{C}$
- HIGH NOISE IMMUNITY:
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{OH}| = I_{OL} = 4\text{mA}$ (MIN)
- BALANCED PROPAGATION DELAYS:
 $t_{PLH} \cong t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE:
 V_{CC} (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE WITH 54 SERIES 154
- SPACE GRADE-1: ESA SCC QUALIFIED
- 50 krad QUALIFIED, 100 krad AVAILABLE ON REQUEST
- NO SEL UNDER HIGH LET HEAVY IONS IRRADIATION
- DEVICE FULLY COMPLIANT WITH SCC-9205-023

DESCRIPTION

The M54HC154 is an high speed CMOS 4 TO 16 LINE DECODER/DEMULTIPLEXER fabricated with silicon gate C²MOS technology.



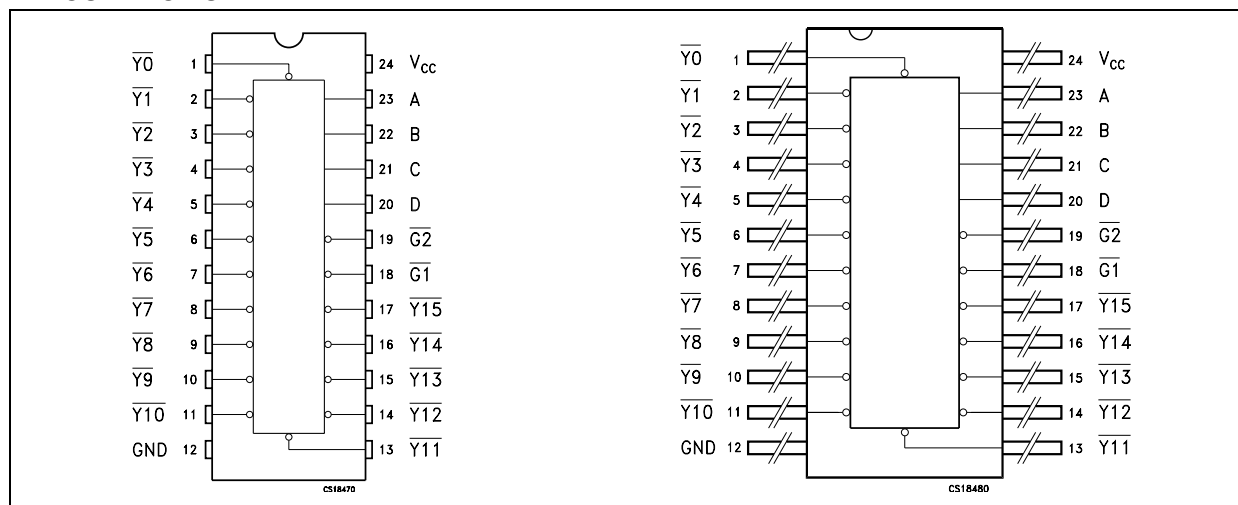
ORDER CODES

PACKAGE	FM	EM
DILC	M54HC154D	M54HC154D1
FPC	M54HC154K	M54HC154K1

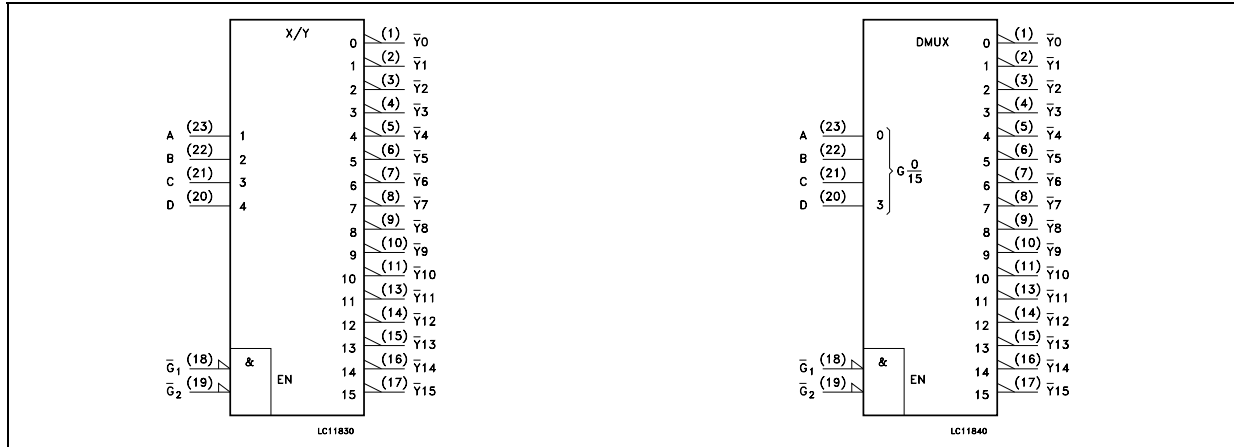
A binary code applied to the four inputs (A to D) provides a low level at the selected one of sixteen outputs excluding the other fifteen outputs, when both the strobe inputs, $\overline{G1}$ and $\overline{G2}$, are held low. When either strobe input is held high, the decoding function is inhibited to keep all outputs high. The strobe function makes it easy to expand the decoding lines through cascading, and simplifies the design of address decoding circuits in memory control systems.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

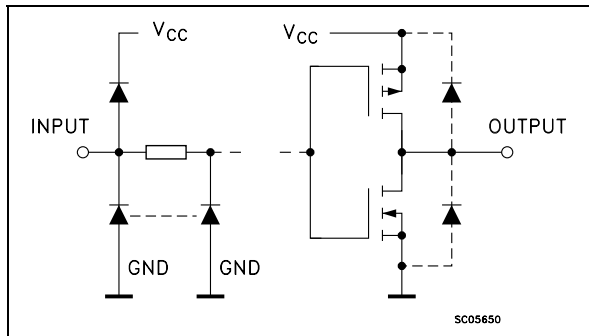
PIN CONNECTION



IEC LOGIC SYMBOLS



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN N°	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11, 13, 14, 15, 16, 17	Y0 to Y15	Outputs (Active Low)
18, 19	G1, G2	Enable Inputs (Active Low)
23, 22, 21, 20	A to D	Address Inputs
12	GND	Ground (0V)
24	Vcc	Positive Supply Voltage

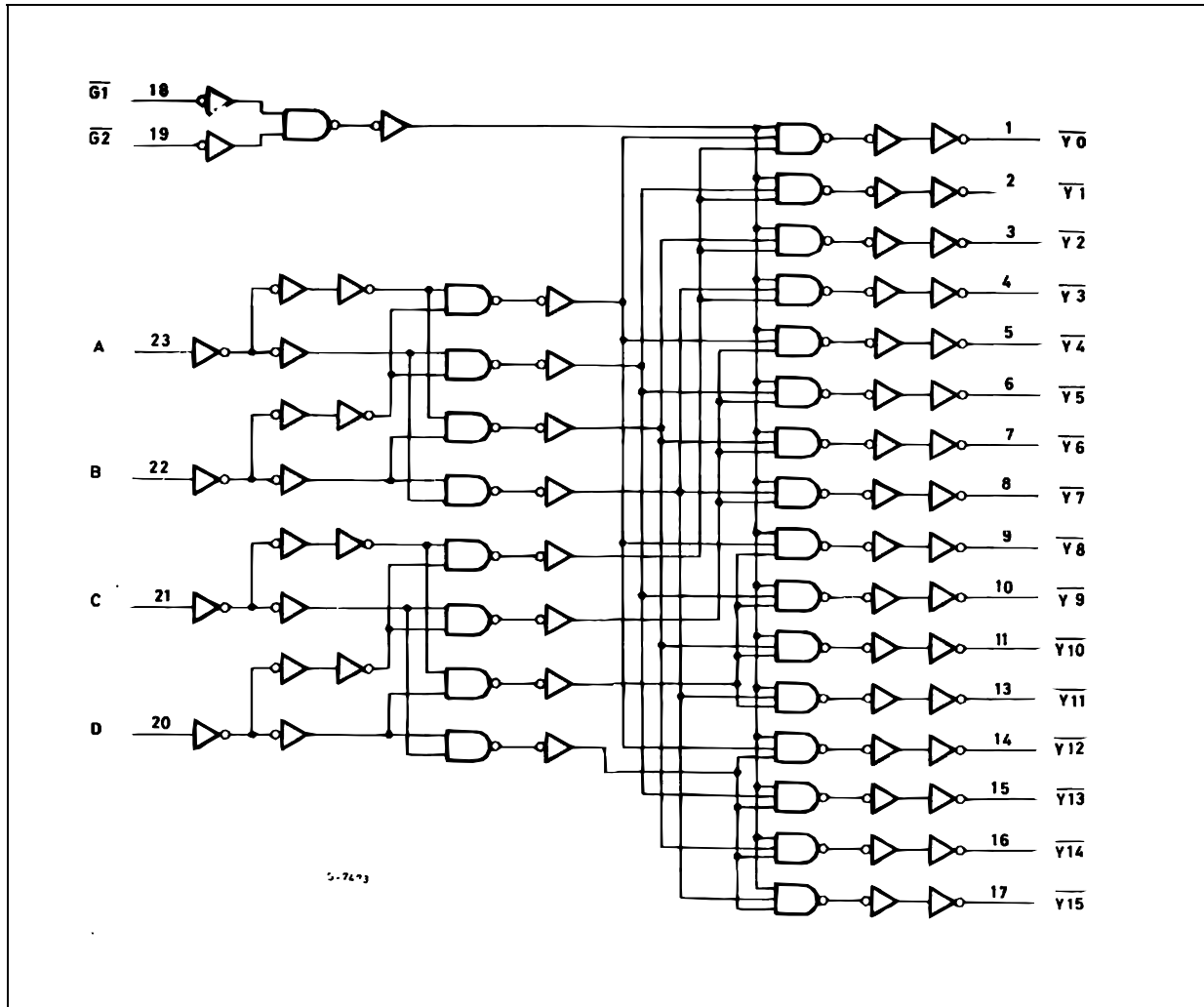
TRUTH TABLE

INPUTS						SELECTED OUTPUT (L)
G1	G2	D	C	B	A	
L	L	L	L	L	L	Y0
L	L	L	L	L	H	Y1
L	L	L	L	H	L	Y2
L	L	L	L	H	H	Y3
L	L	L	H	L	L	Y4
L	L	L	H	L	H	Y5
L	L	L	H	H	L	Y6
L	L	L	H	H	H	Y7
L	L	H	L	L	L	Y8
L	L	H	L	L	H	Y9
L	L	H	L	H	L	Y10
L	L	H	L	H	H	Y11
L	L	H	H	L	L	Y12
L	L	H	H	L	H	Y13
L	L	H	H	H	L	Y14
L	L	H	H	H	H	Y15
X	H	X	X	X	X	NONE
H	X	X	X	X	X	NONE

X : Don't Care



LOGIC DIAGRAM



This logic diagram has not be used to estimate propagation delays

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	300	mW
T_{stg}	Storage Temperature	-65 to +150	$^{\circ}C$
T_L	Lead Temperature (10 sec)	265	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit	
V_{CC}	Supply Voltage	2 to 6	V	
V_I	Input Voltage	0 to V_{CC}	V	
V_O	Output Voltage	0 to V_{CC}	V	
T_{op}	Operating Temperature	-55 to 125	°C	
t_r, t_f	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000	ns
		$V_{CC} = 4.5V$	0 to 500	ns
		$V_{CC} = 6.0V$	0 to 400	ns

DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V_{IH}	High Level Input Voltage	2.0		1.5			1.5				V
		4.5		3.15			3.15				
		6.0		4.2			4.2				
V_{IL}	Low Level Input Voltage	2.0				0.5		0.5			V
		4.5				1.35		1.35			
		6.0				1.8		1.8			
V_{OH}	High Level Output Voltage	2.0	$I_O = -20 \mu\text{A}$	1.9	2.0		1.9				V
		4.5	$I_O = -20 \mu\text{A}$	4.4	4.5		4.4				
		6.0	$I_O = -20 \mu\text{A}$	5.9	6.0		5.9				
		4.5	$I_O = -4.0 \text{ mA}$	4.18	4.31		4.13				
		6.0	$I_O = -5.2 \text{ mA}$	5.68	5.8		5.63				
V_{OL}	Low Level Output Voltage	2.0	$I_O = 20 \mu\text{A}$		0.0	0.1		0.1			V
		4.5	$I_O = 20 \mu\text{A}$		0.0	0.1		0.1			
		6.0	$I_O = 20 \mu\text{A}$		0.0	0.1		0.1			
		4.5	$I_O = 4.0 \text{ mA}$		0.17	0.26		0.33			
		6.0	$I_O = 5.2 \text{ mA}$		0.18	0.26		0.33			
I_I	Input Leakage Current	6.0	$V_I = V_{CC}$ or GND			± 0.1		± 1		μA	
I_{CC}	Quiescent Supply Current	6.0	$V_I = V_{CC}$ or GND			4		40	80	μA	

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

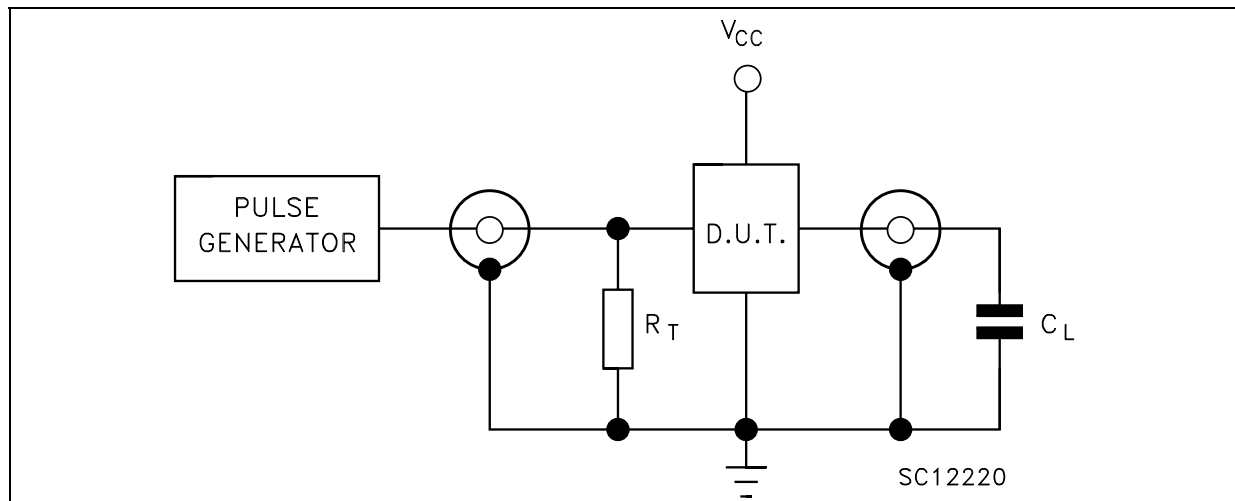
Symbol	Parameter	Test Condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t_{TLH} t_{THL}	Output Transition Time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_{PLH} t_{PHL}	Propagation Delay Time (A, B, C, D - \bar{Y})	2.0			65	125		155		300	ns
		4.5			19	25		31		60	
		6.0			16	21		26		51	
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{G1}$, $\overline{G2}$ - Y)	2.0			55	160		200		265	ns
		4.5			17	32		40		53	
		6.0			15	27		34		45	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
C_{IN}	Input Capacitance	5.0			5	10		10			pF
C_{PD}	Power Dissipation Capacitance (note 1)	5.0			57						pF

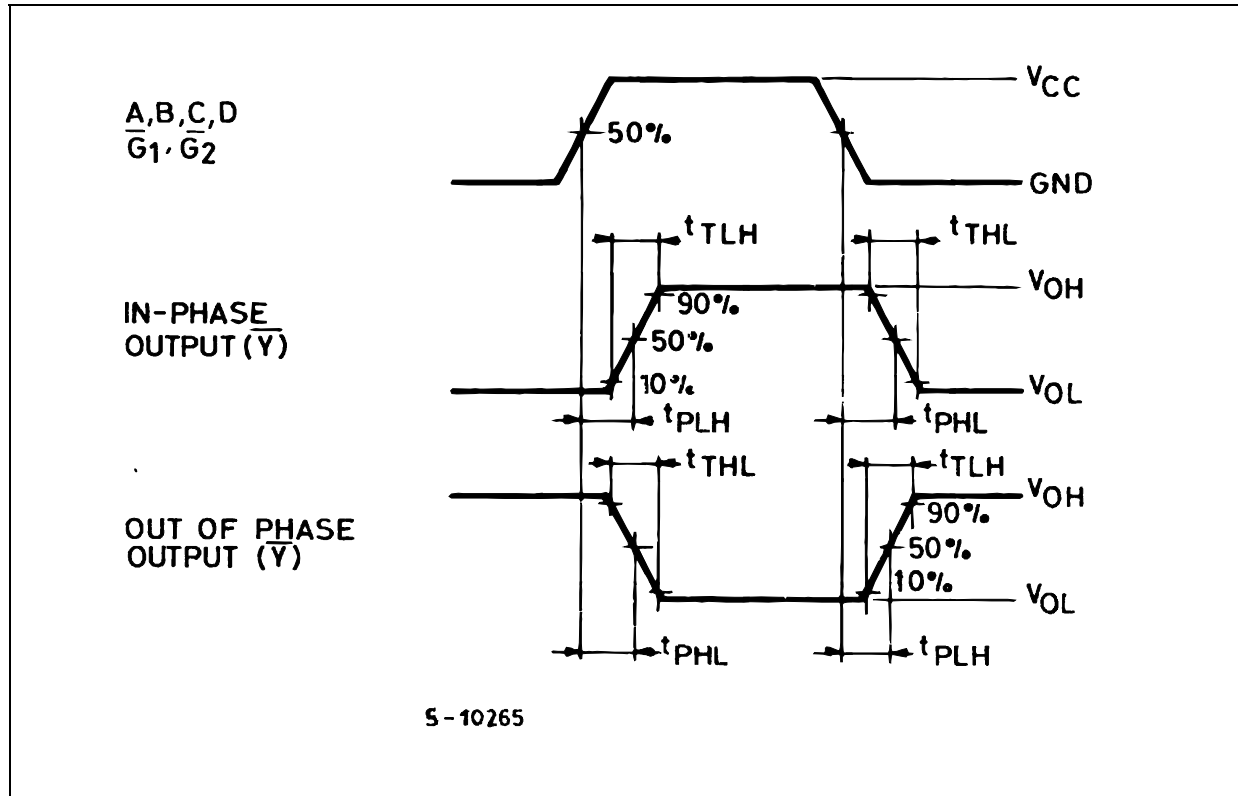
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(oper)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

TEST CIRCUIT



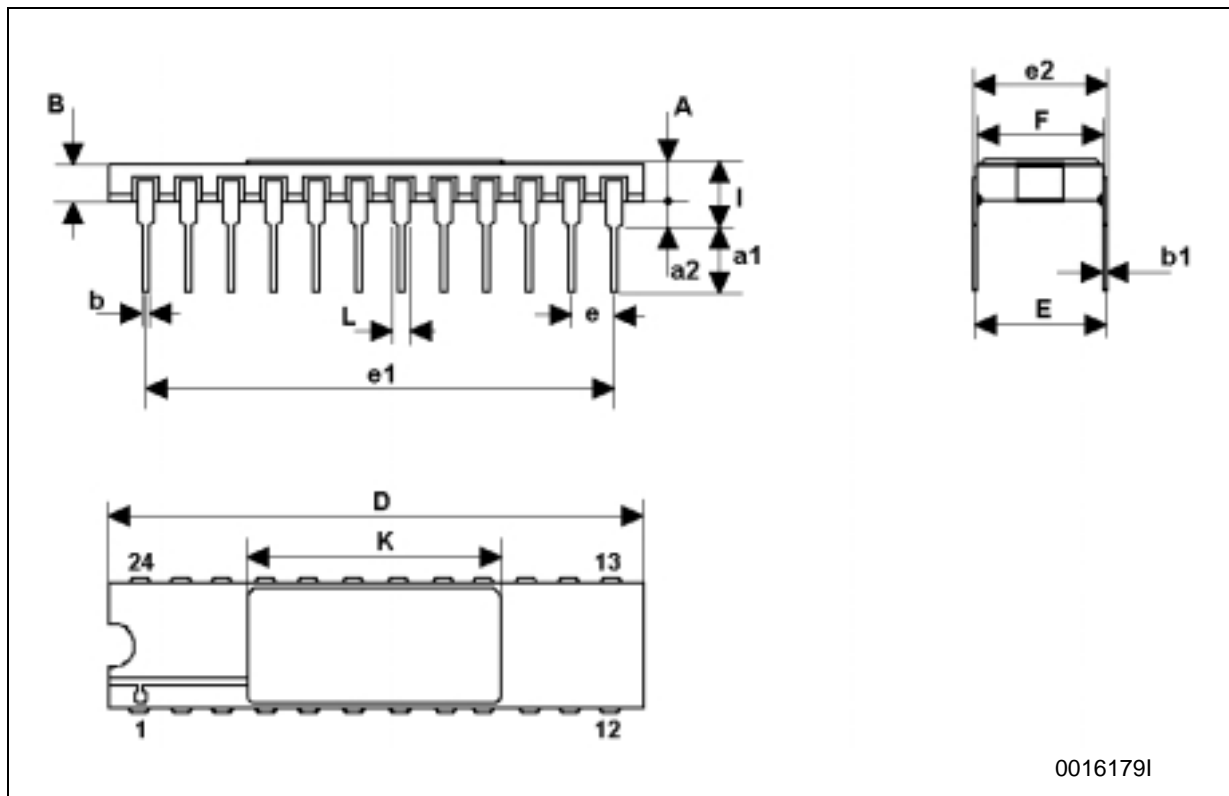
$C_L = 50 \text{ pF}$ or equivalent (includes jig and probe capacitance)
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

WAVEFORM 1: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



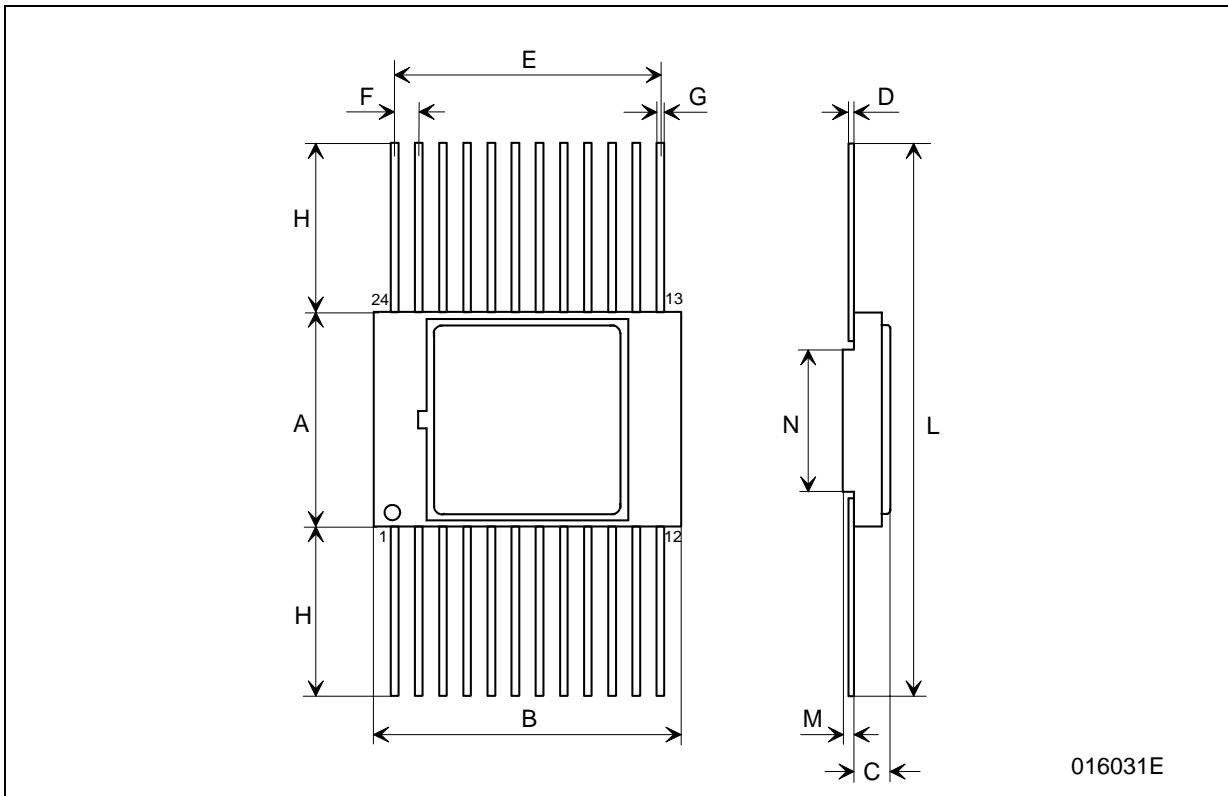
DILC-24 (0.3") MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	2.1		2.72	0.083		0.107
a1	2.7	3.0	3.3	0.106	0.118	0.130
a2	1.016	1.27	1.524	0.40	0.50	0.60
B	1.93	2.16	2.39	0.076	0.85	0.094
b	0.40	0.45	0.50	0.016	0.018	0.020
b1	0.20	0.254	0.30	0.008	0.010	0.012
D	30.17	30.48	30.78	1.188	1.200	1.212
e	7.36	7.62	7.87	0.290	0.300	0.310
e1		2.54			0.100	
e2	27.81		28.07	1.095		1.105
e3	7.62	7.87	8.12	0.300	0.310	0.320
F	7.24		7.75	0.285		0.305
I			4.24			0.167
K	14.22		14.48	0.560		0.570
L	1.22	1.27	1.32	0.048	0.050	0.052



FPC-24 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	10.70	11.0	11.30	0.421	0.433	0.445
B	15.3	15.49	15.70	0.602	0.610	0.618
C	1.45		1.9	0.057		0.075
D	0.23	0.254	0.3	0.009	0.010	0.012
E	13.84	13.97	14.10	0.545	0.550	0.555
F	1.22	1.27	1.32	0.048	0.050	0.052
G	0.45	0.508	0.55	0.018	0.020	0.022
H	7.25		8.25	0.285		0.325
L	25.0		28.0	0.984		1.102
M	0.45	0.508	0.55	0.018	0.020	0.022
N		7.01			0.276	



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